## NSN 5961-00-086-8053

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View Online at https://aerobasegroup.com/nsn/5961-00-086-8053 **Inclosure Material:** Glass and metal **Overall Length:** Between 0.200 inches and 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.290 inches and 0.370 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 breakover voltage, dc **Current Rating Per Characteristic:** 5.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0